


**TRANSMITTAL**

Electronic Version v1.1

Stylesheet Version v1.1.0

<b>Title of Invention</b>	Method of Improved High K Dielectric-Polysilicon Interface for CMOS Devices	
Application Number :	09/941827	
Date :	2001-08-29	
First Named Applicant:	Weimer Ronald A.	
Confirmation Number:	7551	
Attorney Docket Number:	MTI-31532	
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Documents being submitted:	Files
us-fee-sheet	MTI-31532-usfees.xml
	us-fee-sheet.xsl
	us-fee-sheet.dtd
us-ids	MTI-31532-usidst.xml
	us-ids.dtd
	us-ids.xsl
Comments	